



# N-Channel 60 V (D-S) Super Junction Power MOSFET

PRODUCT SUMMARY						
V <sub>DS</sub> (V)	$R_{DS(on)}$ (m $\Omega$ )(Typ.) $I_D$ (A) <sup>a</sup>					
60	2.1 at V <sub>GS</sub> = 10 V	160				
00	3.5 at V <sub>GS</sub> = 4.5 V	100				

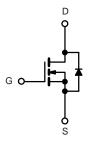
#### **FEATURES**

- 175 °C Junction Temperature
- DT-SJ Power MOSFET
- 100% UIS and 100% Rg Tested

# RoHS

#### **APPLICATIONS**

- · Boost converters
- Industrial power supplies



N-Channel MOSFET

TO-220	Pin	Configuration
	Top	View



ABSOLUTE MAXIMUM RATINGS (T <sub>C</sub> = 25 °C, unless otherwise noted)							
Parameter	Symbol	Limit	Unit				
Gate-Source Voltage	$V_{GS}$	± 20	V				
Continuous Drain Current (T <sub>.I</sub> = 175 °C) <sup>b</sup>	T <sub>C</sub> = 25 °C	I.	160				
Continuous Drain Current (1 <sub>J</sub> = 175 °C) <sup>2</sup>	T <sub>C</sub> = 100 °C	I <sub>D</sub>	120 <sup>a</sup>	]			
Pulsed Drain Current	I <sub>DM</sub>	520	Α				
Continuous Source Current (Diode Conduction)	I <sub>S</sub>	160 <sup>a</sup>					
Avalanche Current	I <sub>AS</sub>	155	]				
Single Avalanche Energy (Duty Cycle ≤ 1 %)	E <sub>AS</sub>	668	mJ				
Maximum Power Dissipation	T <sub>C</sub> = 25 °C	P <sub>D</sub> 230		W			
Maximum Fower Dissipation	T <sub>A</sub> = 25 °C	' D	3.3 <sup>b</sup>	] vv			
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	- 55 to 175	°C				

THERMAL RESISTANCE RATINGS								
Parameter		Symbol	Typical	Maximum	Unit			
M ·	t ≤ 10 sec	<b>D</b>	13	18	°C/W			
Maximum Junction-to-Ambient <sup>a</sup>	Steady State	$R_{thJA}$	38	50				
Maximum Junction-to-Case	·	R <sub>thJC</sub>	0.8	1.1				

#### Notes:

- a. Package limited.
- b. Surface mounted on 1" x 1" FR4 board.
- c.  $t \le 10 \text{ s}$ .

Rev. C1 1





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<b>SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C, unless otherwise noted)									
Parameter	Symbol	Min.	Typ.a	Max.	Unit				
Static			•						
Drain-Source Breakdown Voltage	$V_{DS}$	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	60	-	-	V			
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	1.5	-	3.5	V			
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	-	-	± 100	nA			
		$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$	-	-	1				
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 48 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 125 °C	-	-	50	μA			
		$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 175 \text{ °C}$	-	-	250				
On-State Drain Current <sup>b</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	160	-	-	Α			
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 20 A	-	2.1	2.8	mΩ			
Davis Ossans Os Olata Davista anh	P	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 20 A, T <sub>J</sub> = 125 °C	-	3	4				
Drain-Source On-State Resistance <sup>b</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 10 A, T <sub>J</sub> = 175 °C	-	3.5	4.5				
		V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 15 A	-	3.5	4.6	1			
Forward Transconductance <sup>b</sup>	9 <sub>fs</sub>	$V_{DS} = 5 \text{ V, } I_{D} = 20 \text{ A}$	-	66	-	S			
Dynamic									
Input Capacitance	C <sub>iss</sub>		-	5970	-	pF			
Output Capacitance	C <sub>oss</sub>	$V_{GS} = 0 \text{ V}, V_{DS} = 30 \text{ V}, f = 1 \text{ MHz}$	-	889	-				
Reverse Transfer Capacitance	C <sub>rss</sub>		-	23	-				
Total Gate Charge <sup>c</sup>	$Q_g$		-	109	-				
Gate-Source Charge <sup>c</sup>	$Q_{gs}$	$V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 20 \text{ A}$	-	83.5	ı	nC			
Gate-Drain Charge <sup>c</sup>	$Q_{gd}$		-	8.5	ı				
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>		-	10	-				
Rise Time <sup>c</sup>	t <sub>r</sub>	$V_{DD} = 30 \text{ V}, R_{L} = 0.6 \Omega$	-	5	-	ns			
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>	$I_D = 20 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 2.5 \Omega$	-	55	-	115			
Fall Time <sup>c</sup>	t <sub>f</sub>		-	12	-				
Source-Drain Diode Ratings and Cha	racteristics (	T <sub>C</sub> = 25 °C)				_			
Pulsed Current	I <sub>SM</sub>		-	-	160	Α			
Diode Forward Voltage	$V_{SD}$	I <sub>F</sub> = 1 A, V <sub>GS</sub> = 0 V	-	0.65	1	V			
Reverse Recovery Time	t <sub>rr</sub>	$I_F = 20 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$	-	45	100	ns			

#### Notes:

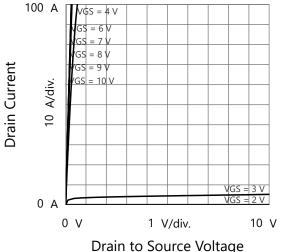
- a. For design aid only; not subject to production testing.
- b. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %.
- c. Independent of operating temperature.

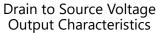
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

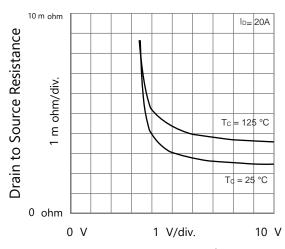




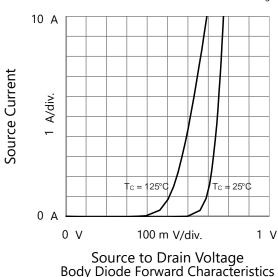
#### TYPICAL CHARACTERISTICS (25 °C unless noted)

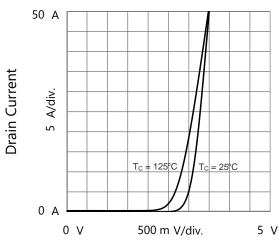




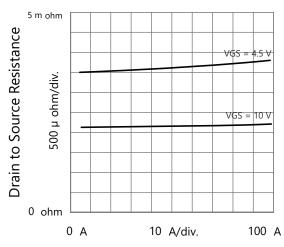


Gate to Source Voltage
Drain to Source Resistance vs. Gate to Source Voltage

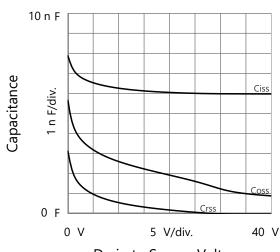




Gate to Source Voltage Transfer Characteristics



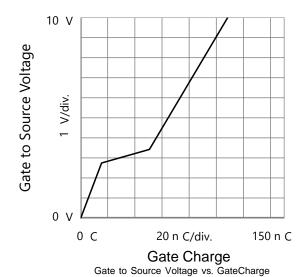
Drain Current
Drain to Source Resistance vs. Drain Current



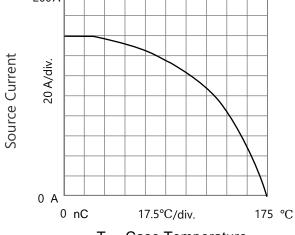
Drain to Source Voltage Capacitances



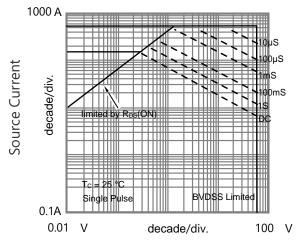
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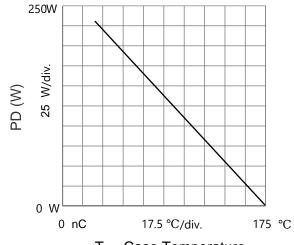




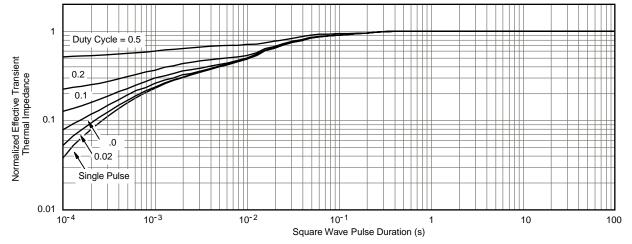
 $T_{C} \textbf{ - Case Temperature}_{\text{Current Derating}}$ 



Source to Drain Voltage Safe Operating Area, Junction-to-Ambient



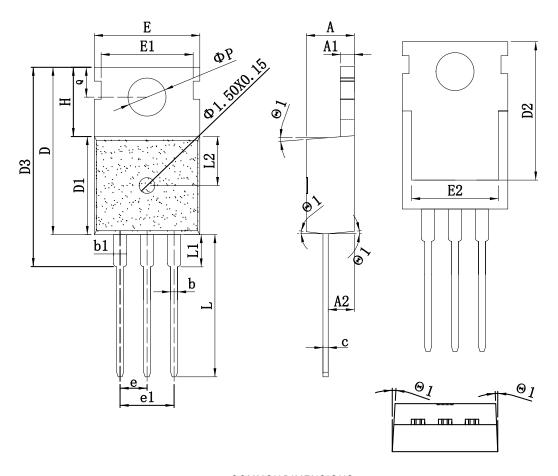
T<sub>C</sub> - Case Temperature Power Derating



Normalized Thermal Transient Impedance, Junction-to-Case



# **TO-220\_3L-A PACKAGE OUTLINE**

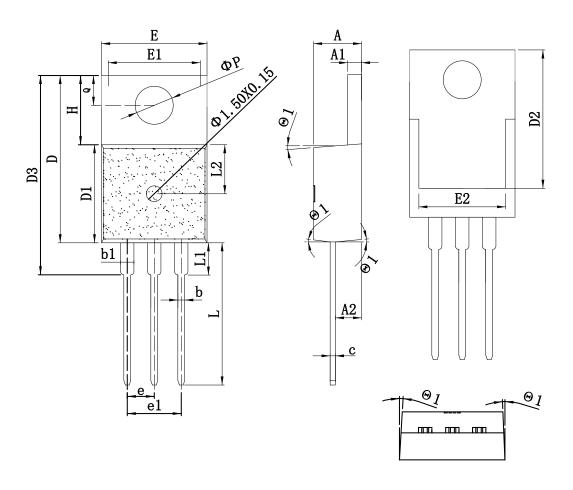


**COMMON DIMENSIONS** (UNITS OF MEASURE=mm)

CVMDOL		mm		CVMDOL	mm			
SYMBOL	MIN	TYP	MAX	SYMBOL	MIN	TYP	MAX	
Α	4.15	4.50	4.80	E1	8.25	8.70	9.15	
A1	1.15	1.30	1.50	E2	7.20	8.00	8.80	
A2	2.10	2.40	2.65	е	2.38	2.54	2.74	
b	0.65	0.80	1.00	e1	5.07 REF			
b1	1.10	1.33	1.80	Н	6.20	6.50	6.90	
С	0.35	0.50	0.65	L	12.75	13.28	13.70	
D	14.25	15.75	16.15	L1	-	-	3.50	
D1	8.70	9.20	9.60	L2	2.30	4.65	7.00	
D2	12.30	13.10	13.85	φР	3.40	3.65	3.85	
D3	16.20	18.80	20.60	Q	2.50	2.80	3.00	
Е	8.68	10.02	11.00	θ	2°	-	7°	



# **TO-220\_3L-B PACKAGE OUTLINE**



**COMMON DIMENSIONS** (UNITS OF MEASURE=mm)

0)/1/10/1		mm	_	SYMBOL	mm			
SYMBOL	MIN	TYP	MAX	STIVIBUL	MIN	TYP	MAX	
А	4.15	4.50	4.80	E1	8.25	8.70	9.15	
A1	1.15	1.30	1.50	E2	7.20	8.00	8.80	
A2	2.10	2.40	2.65	е	2.38	2.54	2.74	
b	0.65	0.80	1.00	e1	5.08 REF			
b1	1.10	1.33	1.80	Н	6.20	6.50	6.90	
С	0.35	0.50	0.65	L	12.75	13.28	13.70	
D	14.25	15.75	16.15	L1	-	-	3.50	
D1	8.70	9.20	9.60	L2	2.30	4.65	7.00	
D2	12.30	13.10	13.85	φР	3.40	3.65	3.85	
D3	16.20	18.80	20.60	Q	2.50	2.80	3.00	
Е	8.68	10.02	11.00	θ	2°	-	7°	





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